## 捷多邦,专业PCB打样工厂,24小时加急出货

## **BC212B**

# **Amplifier Transistors**

**PNP Silicon** 

#### Features

• These are Pb–Free Devices\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	-50	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	-60	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Collector Current – Continuous	۱ <sub>C</sub>	-100	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	350 2.8	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	1.0 8.0	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	357	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	125	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

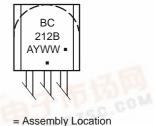


## **ON Semiconductor®**

http://onsemi.com



#### MARKING DIAGRAM



= Assembly Location

= Work Week

WW

= Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
BC212BG	TO-92 (Pb-Free)	5000 Units / Bulk
BC212BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Provide the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

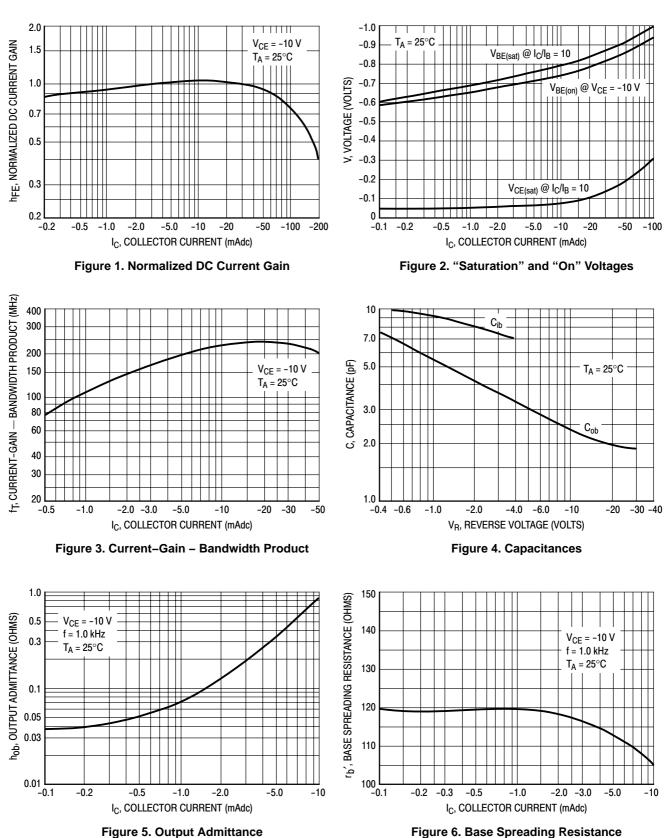
## BC212B

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Collector – Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	-50	-	-	Vdc
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-60	-	-	Vdc
Emitter – Base Breakdown Voltage	V <sub>(BR)EBO</sub>	-5	-	-	Vdc
Collector-Emitter Leakage Current	I <sub>CBO</sub>	-	-	-15	nAdc
Emitter-Base Leakage Current	I <sub>EBO</sub>	-	_	-15	nAdc
ON CHARACTERISTICS		•			•
DC Current Gain (I <sub>C</sub> = -10 $\mu$ Adc, V <sub>CE</sub> = -5.0 Vdc)	h <sub>FE</sub>	40	_	_	-
$(I_{C} = -2.0 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$		60	_	_	
(I <sub>C</sub> = -100 mAdc, V <sub>CE</sub> = -5.0 Vdc) (Note 1)		-	120	-	
Collector – Emitter Saturation Voltage ( $I_C = -10 \text{ mAdc}, I_B = -0.5 \text{ mAdc}$ ) ( $I_C = -100 \text{ mAdc}, I_B = -5.0 \text{ mAdc}$ ) (Note 1)	V <sub>CE(sat)</sub>		-0.10 -0.25	-0.6	Vdc
Base – Emitter Saturation Voltage ( $I_C = -100 \text{ mAdc}, I_B = -5.0 \text{ mAdc}$ )	V <sub>BE(sat)</sub>	-	-1.0	-1.4	Vdc
Base–Emitter On Voltage ( $I_C = -2.0 \text{ mAdc}$ , $V_{CE} = -5.0 \text{ Vdc}$ )	V <sub>BE(on)</sub>	-0.6	-0.62	-0.72	Vdc
DYNAMIC CHARACTERISTICS			1		•
Current-Gain – Bandwidth Product ( $I_C = -10 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc}, f = 100 \text{ mHz}$ )	f <sub>T</sub>	_	280	-	MHz
Common–Base Output Capacitance ( $V_{CB} = -10$ Vdc, $I_C = 0$ , f = 1.0 mHz)	C <sub>ob</sub>	-	-	6.0	pF
Noise Figure (I <sub>C</sub> = -0.2 mAdc, V <sub>CE</sub> = -5.0 Vdc, R <sub>S</sub> = 2.0 k $\Omega$ , f = 1.0 kHz, f = 200 Hz)	NF	-	-	10	dB
Small–Signal Current Gain ( $I_C = -2.0$ mAdc, $V_{CE} = -5.0$ Vdc, f = 1.0 kHz)	h <sub>fe</sub>	200	_	400	_

1. Pulse Test: Tp 300 s, Duty Cycle 2.0%.

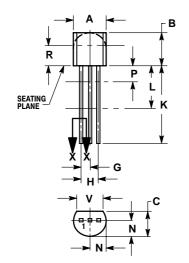
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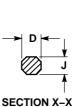


## **BC212B**

#### PACKAGE DIMENSIONS







STRAIGHT LEAD **BULK PACK** 

NOTES: DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- 3.
- TIA3M, 1962. CONTROLLING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND 4 BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
Κ	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
۷	0.135		3.43	

в R Т SEATING PLANE G

BENT LEAD TAPE & REEL AMMO PACK



NOTES 1. DIMENSIONING AND TOLERANCING PER

ASME Y14.5M, 1994 CONTROLLING DIMENSION: MILLIMETERS.

- 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM. 4.

	MILLIMETERS		
DIM	MIN MAX		
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
ſ	0.39	0.50	
K	12.70		
Ν	2.04	2.66	
Р	1.50	4.00	
R	2.93		
V	3.43		

STYLE 17: PIN 1. COLLECTOR BASE 2. EMITTER 3.

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